

HVL144AM

Silicon Epitaxial Trench Pin Diode for Antenna Switching

REJ03G0199-0200

Rev.2.00

Jan 20, 2006

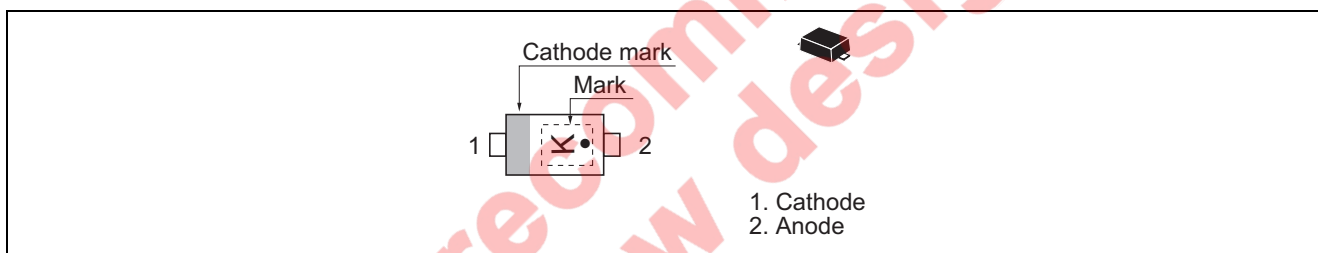
Features

- Adopting the trench structure improves low capacitance.(C = 0.43 pF max)
- Low forward resistance. (rf = 1.8 Ω max)
- Low operation current.
- Thin Extremely small Flat Lead Package (TEFP) is suitable for surface mount design.

Ordering Information

Type No.	Laser Mark	Package Name	Package Code
HVL144AM	K	TEFP	PUSF0002ZA-A

Pin Arrangement



Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Value	Unit
Reverse voltage	V_R	30	V
Forward current	I_F	100	mA
Power dissipation	P_d	100	mW
Junction temperature	T_j	125	°C
Storage temperature	T_{stg}	-55 to +125	°C

Electrical Characteristics

(Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse current	I_R	—	—	100	nA	$V_R = 30\text{ V}$
Forward voltage	V_F	—	—	0.90	V	$I_F = 2\text{ mA}$
Capacitance	C	—	—	0.43	pF	$V_R = 1\text{ V}$, $f = 1\text{ MHz}$
Forward resistance	r_f	—	—	1.80	Ω	$I_F = 2\text{ mA}$, $f = 100\text{ MHz}$
ESD-Capability * ¹	—	100	—	—	V	$C = 200\text{ pF}$, $R = 0\text{ }\Omega$, Both forward and reverse direction 1 pulse.

Notes: 1. Failure criterion ; $I_R > 100\text{ nA}$ at $V_R = 30\text{ V}$

2. For TEPF package, the material of lead is exposed for cutting plane. There for, soldering nature of lead tip part is considered as unquestioned. Please kindly consider soldering nature.

Main Characteristic

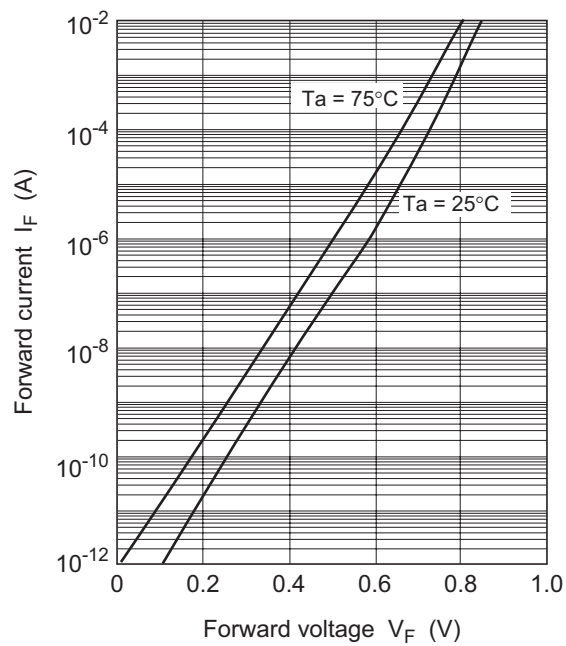


Fig.1 Forward current vs. Forward voltage

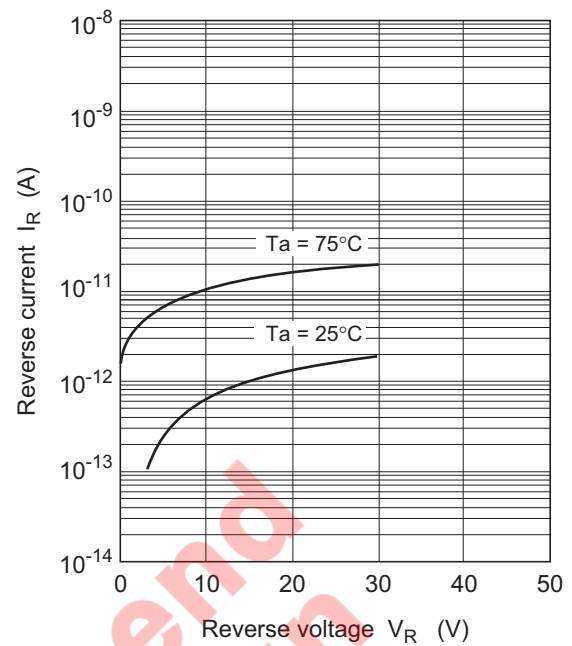


Fig.2 Reverse current vs. Reverse voltage

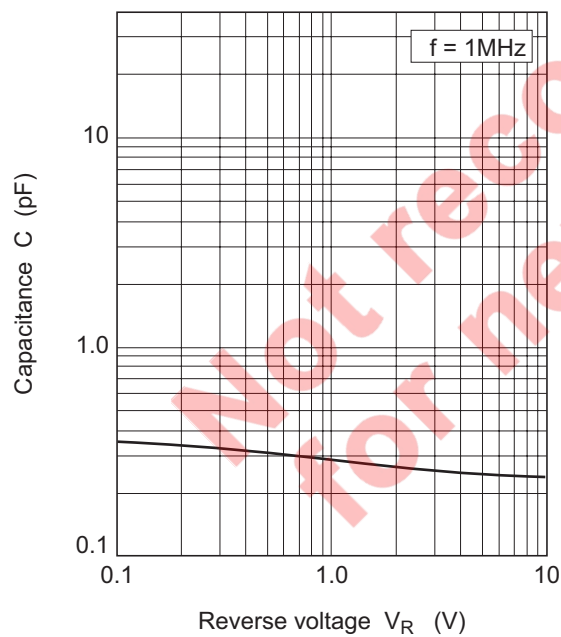


Fig.3 Capacitance vs. Reverse voltage

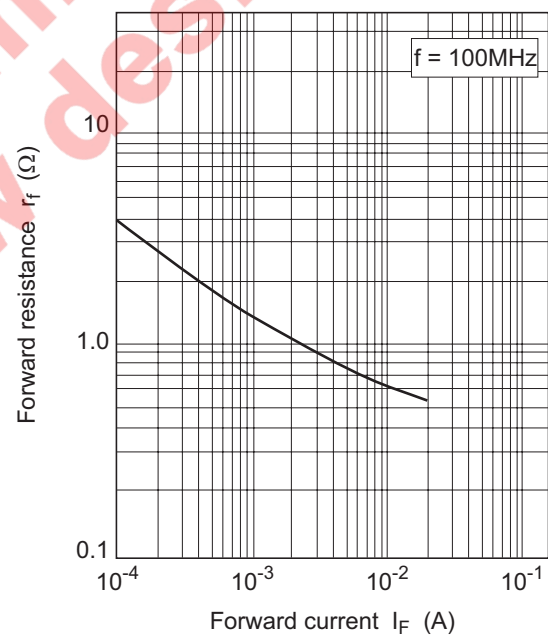


Fig.4 Forward resistance vs. Forward current

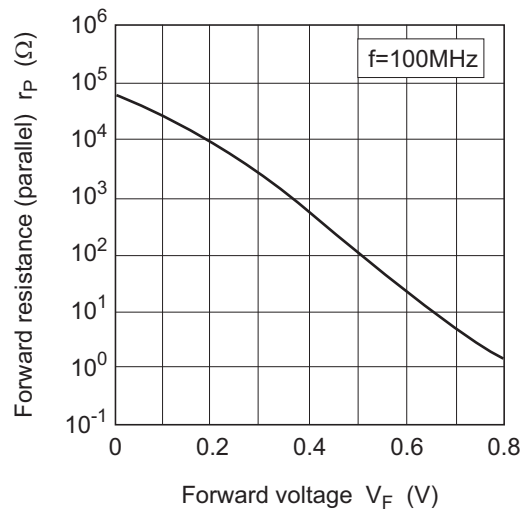
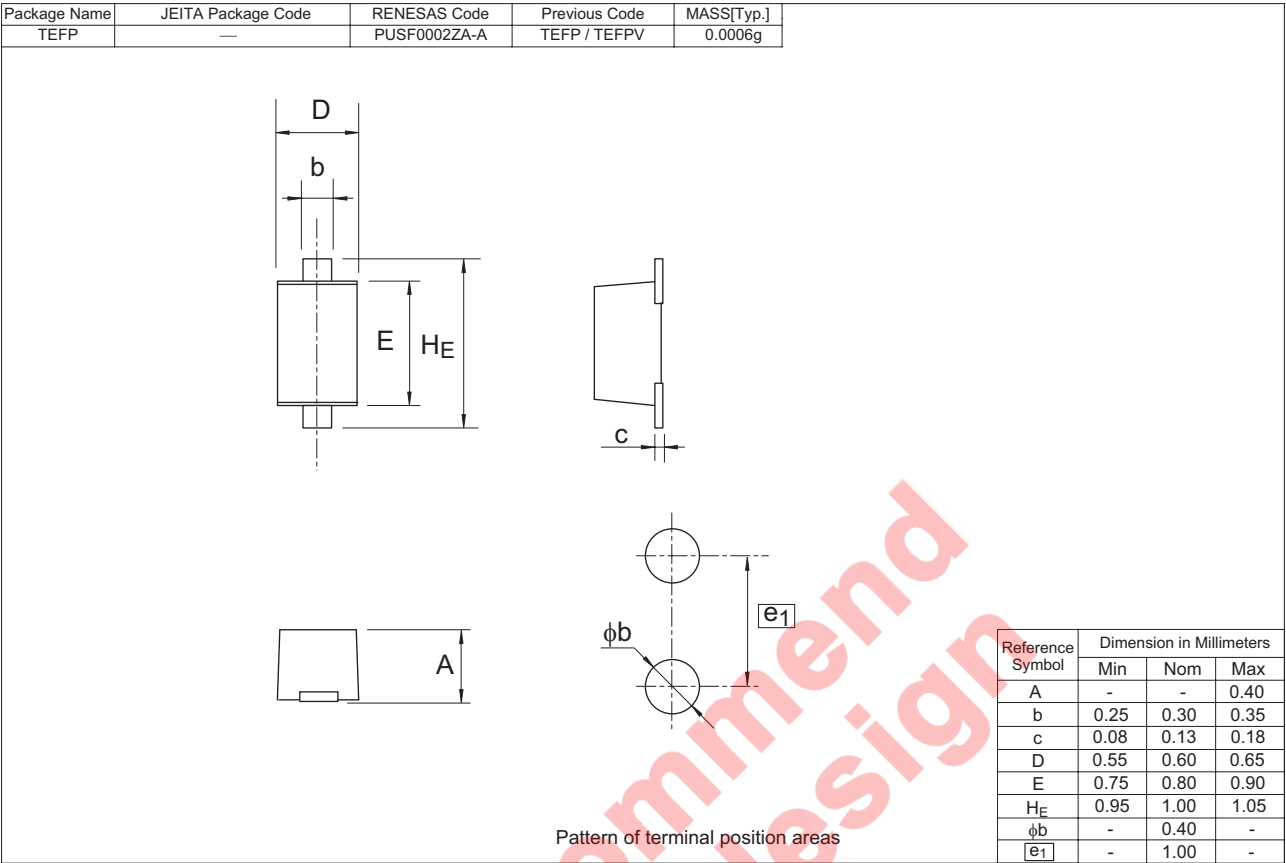


Fig.5 Forward resistance (parallel) vs. Forward voltage

Not recommended
for new design

Package Dimensions



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